

1 Near Bragg : Hydrid particle-wave approach

An alternative approach to the multislice algorithm consists in solving (??) approximately using an extension of the kinematic theory to multiple scattering. This method is called near-bragg(NB) and initially developed for X-rays [?].

Each atom scatter the incident electron beam according to its electron-atom scattering cross section. The path length of the incident beam is computed and interference at computed at selected pixels on a detector some distance away from the sample.

1.1 Scattering by individual atoms

The first order approximation yields the kinematic theory of diffraction also known as first Born approximation. It is a perturbation treatment often used to allow for an analytical treatment. The incident state ϕ is used in place of Ψ in the right hand side so that the scattering equation can readily be solved as :

$$\Psi(\mathbf{r}) = e^{ikz} + f(\theta) \frac{e^{i\mathbf{k}\cdot\mathbf{r}}}{|\mathbf{r}|} \quad (1)$$

where :

$$f(\theta) = -\frac{2me}{h^2} \int d^3r e^{i\mathbf{q}\cdot\mathbf{r}} V(r) \quad , \quad \frac{d\sigma}{d\Omega} = |f(\theta)|^2 \quad (2)$$

where $f(\theta)$ is the scattering amplitude, i.e. the Fourier transform of the electrostatic potential. In the first Born approximation the far field diffraction pattern is proportional to the square of the scattering amplitude which is known as the differential cross section σ .

1.2 Central beam calculation

With the MS method, the intensity of the central beam corresponds to the sum of the forward scattering beam and the incident coherent unscattered beam. On the other hand, NB is based on path length calculation to compute the scattered beams contribution to the diffraction pattern. The central unscattered beam and the central forward scattered beam are therefore computed separately. Below, the scattering cross section is used to determine the amount of unscattered beam and will be subsequently used for proper bookkeeping in the implementation of double scattering.

1.2.1 Cross section, mean free path and scattering probabilities

In a continuous medium, the probability of an electron to undergo m elastic collisions and n inelastic collisions after going through a specimen of length z follows the Poisson distribution [?]:

$$P_{mn}(z) = \frac{1}{m!} \left(\frac{z}{l_e} \right)^m e^{-z/l_e} \frac{1}{n!} \left(\frac{z}{l_i} \right)^n e^{-z/l_i} \quad (3)$$

where $l_e = 1/\sigma_e \rho$ is the average elastic collision mean free path $\sigma_e = |f_a^{(e)}|^2$ being the interaction cross section and $f_a^{(e)}$ the atomic elastic scattering factor, l_i the average inelastic collision mean free path and ρ is the number of atoms per unit volume (per unit area in 2D).

For a typical protein, $\rho = 106$ atoms per nm^3 , the average scattering cross section $\sigma_e = 0.001 - 0.005 A^2$ (within beam energy range $E = 100 - 1000 keV$) resulting in mean free path on the order of $l_e = 200 - 1000 nm$. The corresponding probabilities (3) are shown figure 1. It is apparent that for the low

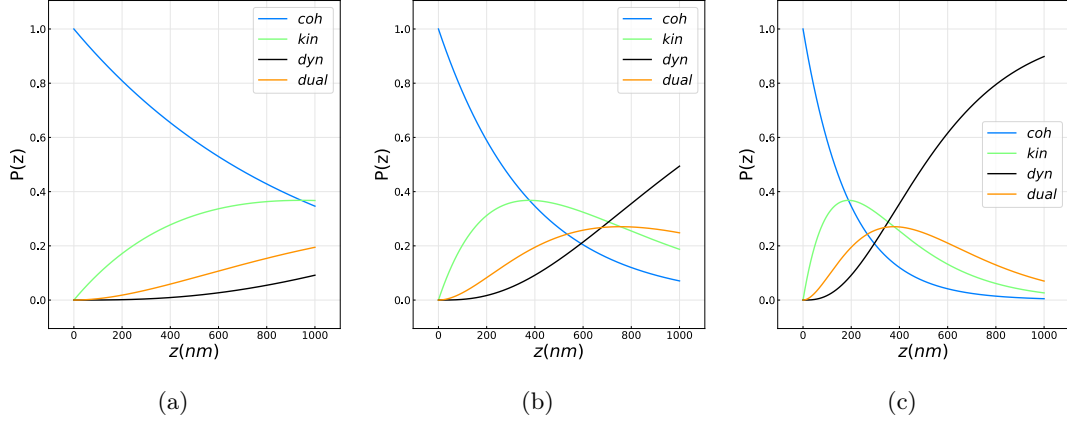


Figure 1: Probability of no scattering(blue), single scattering, i.e. kinematic scattering(green), double scattering(orange) and multiple scattering(solid black) as a function of crystal thickness for a typical protein crystal with average cross section and mean free path 1a $\sigma_e = 0.001\text{\AA}^2, l_e = 943\text{nm}$, 1b $\sigma_e = 0.003\text{\AA}^2, l_e = 377\text{nm}$, 1c $\sigma_e = 0.005\text{\AA}^2, l_e = 188\text{nm}$.

1.2.2 Application in Near Bragg

Considering a primitive orthorhombic lattice with parameters a_x, b_z , a single atom per unit cell, with cross section σ_e the probability of the unscattered beam is found at cell $N + 1$ from cell N as :

$$P_{N+1}^{(coh)} = P_N^{(coh)} \left(1 - \frac{dz}{l_e} \right) = P_N^{(coh)} \left(1 - \frac{\sigma_e}{a_x} \right) \quad (4)$$

where $l_e = a_x b_z / \sigma_e$ and $dz = b_z$. The solution of (4) when $dz \rightarrow 0$ results in (3) for $m = 0$.

In MS, the intensity I_0 is normalized so it integrates to unity over the transverse plane and therefore represents the density of probability of the electron. For a structure with a basis and N_x transverse unit cells, the atoms are arranged in slices of n_k atoms. The incident plane wave intensity is therefore $I_0 = 1/N_x a_x$ and the probability of an electron of being unscattered is originally $P_0^{(coh)} = 1$ and the other scattering probabilities $P_0^{(scat)} = 0$.

The fraction of electrons scattered per unit time by the array of atoms in slice k is $P_k^{(scat)} = \sum_{j=1}^{n_k} \sigma_e(j) I_0$. The number of unscattered electrons per unit time left after going through the slice k is $P_{k+1}^{(coh)} = P_k^{(coh)} - P_k^{(scat)}$ and the unscattered intensity after going through the slice is $I_0 = P_{k+1}^{(coh)} / N_x a_x$. The evolution of the probability of an electron for being unscattered at slice $k + 1$ after going through slice k is therefore :

$$P_{k+1}^{(coh)} = P_k^{(coh)} \left(1 - \sum_{j=1}^{N_k} \frac{\sigma_e(j)}{N_x a_x} \right) \quad (5)$$

1.3 Kinematic calculation

In the kinematic approximation, every atom contributes once (single scattering) to the interference pattern at the detector. More precisely, the contribution of atom j to the intensity value at detector pixel i is given by the interference term $\exp(ik_0 R_{ij}) / R_{ij}$ where R_{ij} is the path length

from atom j to pixel i . It is written with increasing level of approximations as :

$$R_{ij} \underset{Greens}{=} \sqrt{(x - x_0)^2 + (z - z_0)^2} \quad (6)$$

$$\underset{Fresnel}{\approx} (z_0 - z) + \frac{(x - x_0)^2}{2(z_0 - z)} \quad (7)$$

$$\underset{Fraunhofer}{\approx} (z_0 - z) + \frac{x_0^2}{2z_0} - \frac{xx_0}{z_0} \quad (8)$$

$$(9)$$

where x_0, z_0 are the pixel positions and x, z are the atom position. For planar illumination, the path length from the source to atom j is z and must be added to the path length.

The angle of scattering is determined with $\sin(\theta) = |x - x_0|/|z - z_0|$ so the atomic form factor $f(k_0 \sin(\theta))$ is used to apply the correct contribution to the scattering amplitude at that pixel.

The validity of the kinematic approximation is established by comparing NB to MS with a simple square structure with lattice constants $a_x = 10, b_z = 5$ with 100×100 unit cells. The strength of the potential is varied to observe the onset of dynamical diffraction.

Figure 2 shows a comparison between MS and NB for a weak potential $\epsilon = 0.001$. In figure 2d, the agreement for a weak potential between the NB and MS diffraction patterns after $50nm$ propagation is good.

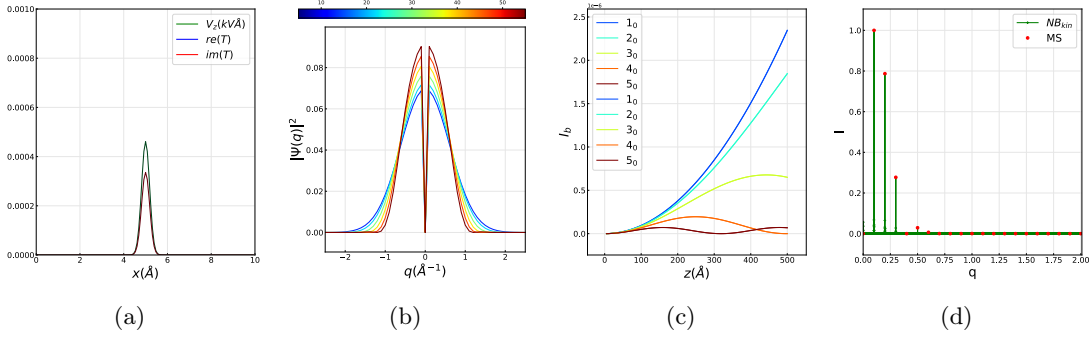


Figure 2: 2a weak potential strength $\epsilon = 0.001$. 2b Evolution of diffraction pattern as function of thickness. 2c Evolution of major beam intensities as function of thickness. 2d comparison of diffraction patterns $t = 50nm$ for NB and MS.

Figure 3 shows on the other hand, that for a stronger potential strength $\epsilon = 0.5$, the NB kinematic approximation is not acceptable after $50nm$ propagation.

1.4 Double scattering calculation

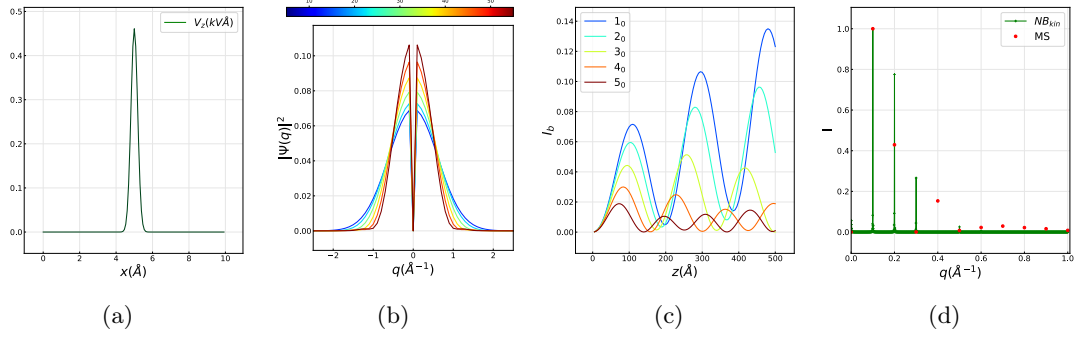


Figure 3: 3a strong potential strength $\epsilon = 0.5$. 3b Evolution of diffraction pattern as function of thickness. 3c Evolution of major beam intensities as function of thickness. 3d comparison of diffraction patterns $t = 50\text{nm}$ for NB and MS.

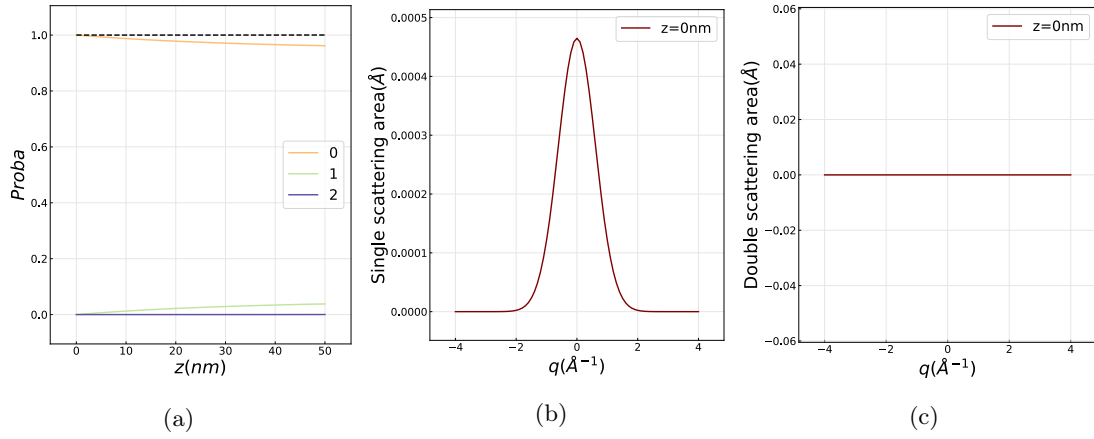


Figure 4: Scattering probabilities in the Near Bragg implementation 4a global, 4b single scattering distribution every 100 slices, 4c same as 4b double scattering.